# MSKSEMI 美森科













**ESD** 

TVS

TSS

MOV

GDT

PIFD

**USBLC6-2SC6-MS** 

**Product specification** 





#### **Description**

The USBLC6-2SC6-MS are monolithic application specific devices dedicated to ESD protection of high speed interfaces, such as USB 2.0, Ethernet links and video lines. The very low line capacitance secures a high le vel of signal integrity without compromising in protecting sensitive chips against the most stringently characterized ESD strikes.

#### Features and benefits

- ESD Protect for 2 high-speed I/O channels
- Provide ESD protechtion for each channel to IEC 61000-4-2(ESD)±30kV(air),±30kV(contact)
- Low Working Voltage: 5.0V
- Low Capacitance: 0.8pF (I/O-GND)
- Low Clamping Voltage
- Response time is typically < 1 ns</li>
- Array of surge rated diodes with internal equivalent TVS diodes
- Small package saves board space
- RoHS compliant

## **Application information**

- Video Graphics Cards
- USB2.0 Power and Data lines protechtion
- 10/100/1000 Ethernet
- Notebooks and PC Computers
- IEEE 1394 Firewire Ports
- Portable electronics
- SIM ports

#### **Reference News**

SOT23-6	Graphic symbol	Marking
1 2 3	GND 2 3 4 102	•UL26



# 

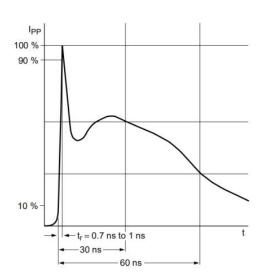
Parameter	Symbol	Value	Unit
Peak Pulse Power (Tp = 8/20μs)	P <sub>PPM</sub>	78	W
Rated Peak Pulse Current (Tp = 8/20µs)	<b>I</b> PPM	6	А
ESD voltage IEC 61000-4-2 (air discharge)	V <sub>ESD</sub>	30	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V <sub>ESD</sub>	30	kV
Maximum lead temperature for soldering during 10s	T∟	260	°C
Storage Temperature Range	$T_{stg}$	-55 to +150	°C
Operating Temperature Range	T <sub>OP</sub>	-40 to +125	°C

# **Electrical Characteristics** (ToP = 25 °C, unless otherwise specified)

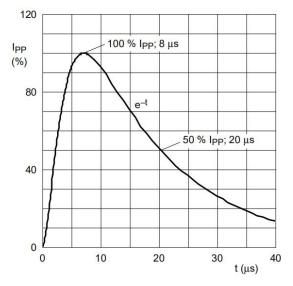
Parameter	Symbol	Min	Тур	Max	Unit	Condition
Reverse Working Voltage	V <sub>RWM</sub>			5.0	V	
Breakdown Voltage	$V_{BR}$	6.5		9.0	V	ե=1mA
Leakage Current ILeak	I <sub>R</sub>			100	nA	V <sub>RWM</sub> =5V
Clamping Voltage(I/O-GND)	Vc		11.0	13.0	V	I <sub>PP</sub> =6A,Tp=8/20μs
Clamping Voltage(VDD-GND)	Vc		11.0	13.0	V	l₀₀=8A,Tp=8/20μs
Junction Capacitance	C <sub>j</sub>		0.4	0.5	pF	V <sub>R</sub> =0V, f=1MHz I/O to I/O
Junction Capacitance	C <sub>j</sub>		0.8	1.0	pF	V <sub>R</sub> =0V, f=1MHz I/O to GND



# TypicalCharacteristics



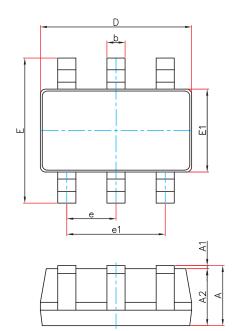
IEC61000-4-2 Waveform

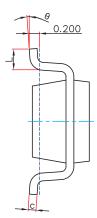


IEC 61000-4-5 Waveform( 8/20µs pulse)



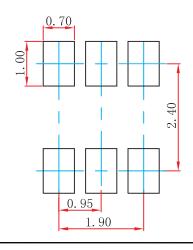
# **SOT-23-6 Package Outline Dimensions**





Symbol	Dimensions In Millimeters		Dimensions In Inches	
Syllibol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950(E	BSC)	0.037(E	BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

# **SOT-23-6 Suggested Pad Layout**



- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

### **REEL SPECIFICATION**

P/N	PKG	QTY
USBLC6-2SC6-MS	SOT-23-6	3000



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